

# **NCE Automotive P-Channel Super Trench Power MOSFET**

## **Description**

The NCEAP01P35AK uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

#### **General Features**

• V<sub>DS</sub> =-100V,I<sub>D</sub> =-35A

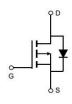
 $R_{DS(ON)}$ =35m $\Omega$  (typical) @  $V_{GS}$ =-10V

 $R_{DS(ON)}$ =40m $\Omega$  (typical) @  $V_{GS}$ =-4.5V

- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- •175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested
- 100% ΔVds tested
- AEC-Q101 qualified

## **Application**

- Automotive application
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification



#### **Schematic Diagram**



Marking and pin assignment



TO-252-2Ltop view

## **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
AP01P35AK	NCEAP01P35AK	TO-252-2L	-	-	-

## Absolute Maximum Ratings (T<sub>C</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	-100	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub>	-35	Α
Drain Current-Continuous(T <sub>C</sub> =100°ℂ)	I <sub>D</sub> (100℃)	-24.5	Α
Pulsed Drain Current	I <sub>DM</sub>	-140	Α
Maximum Power Dissipation	P <sub>D</sub>	105	W
Derating factor		0.7	W/℃
Single pulse avalanche energy (Note 1)	E <sub>AS</sub>	320	mJ
Operating Junction and Storage Temperature Range	$T_{J},T_{STG}$	-55 To 175	$^{\circ}$

#### **Thermal Characteristic**

Thermal Resistance,Junction-to-Case	R <sub>0</sub> JC	1.43	°C/W
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# Electrical Characteristics (T<sub>C</sub>=25 °C unless otherwise noted)

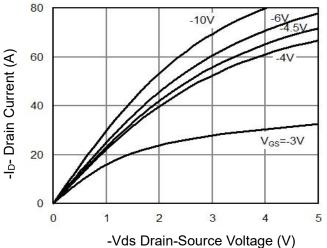
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			<u>'</u>			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA	-100	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-100V,V <sub>GS</sub> =0V	-	-	-1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20 $V$ , $V_{DS}$ =0 $V$	-	-	±100	nA
On Characteristics			<u>'</u>			
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS},I_{D}=-250\mu A$	-1.0	-1.7	-2.2	V
David Course On Otata Basistana		V <sub>GS</sub> =-10V, I <sub>D</sub> =-20A	-	35	45	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA -10 V <sub>DS</sub> =-100V,V <sub>GS</sub> =0V - V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V - V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250μA -1.0	-	40	50	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =-5V,I <sub>D</sub> =-20A	-	20	-	S
Dynamic Characteristics			•	,		
Input Capacitance	Clss	50///	-	3445	-	pF
Output Capacitance	Coss	, , ,	-	260	-	pF
Reverse Transfer Capacitance	Crss	F=1.UMHZ	-	6	-	pF
Switching Characteristics (Note 2)	,		'			1
Turn-on Delay Time	t <sub>d(on)</sub>		-	12.5	-	nS
Turn-on Rise Time	t <sub>r</sub>	·	-	10	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>		-	45	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	12	-	nS
Total Gate Charge	Qg	V 50V/1 00A	-	34.5	-	nC
Gate-Source Charge	Q <sub>gs</sub>	,	-	8.5	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =-10V	-	4.0	-	nC
Drain-Source Diode Characteristics	1		'			
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-20A	-		-1.2	V
Diode Forward Current	Is		-	-	-35	Α
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> =-20A	-	50	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs	-	90	-	nC

#### Notes:

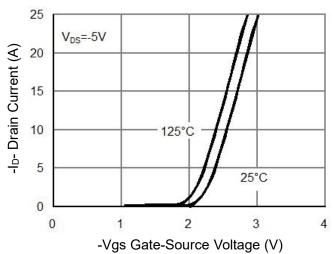
- 1. EAS condition : Tj=25  $^{\circ}\text{C}$  ,VDD=-50V,VG=-10V,L=0.5mH,Rg=25 $\Omega$
- 2. Guaranteed by design, not subject to production
- 3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of TJ(MAX)=150°C. The SOA curve provides a single pulse rating.



# **Typical Electrical and Thermal Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

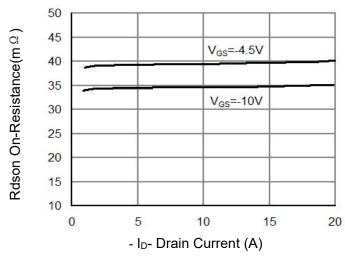


Figure 3 Rdson- Drain Current

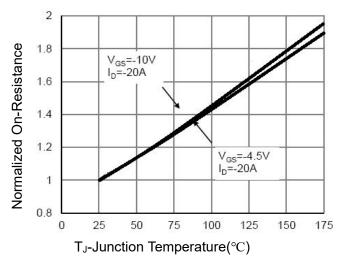
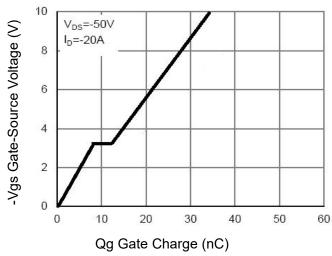


Figure 4 Rdson-JunctionTemperature



**Figure 5 Gate Charge** 

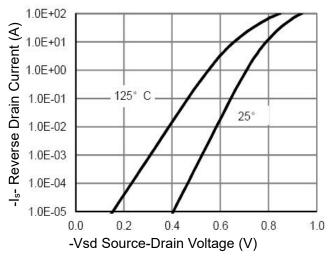
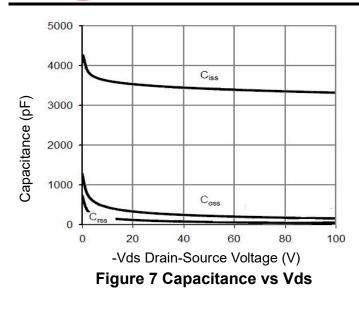


Figure 6 Source- Drain Diode Forward





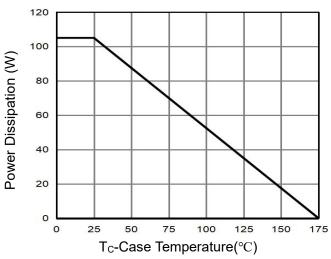
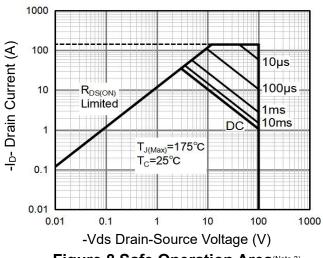


Figure 9 Power De-rating



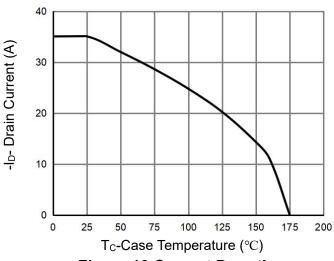


Figure 8 Safe Operation Area(Note 3)

Figure 10 Current De-rating

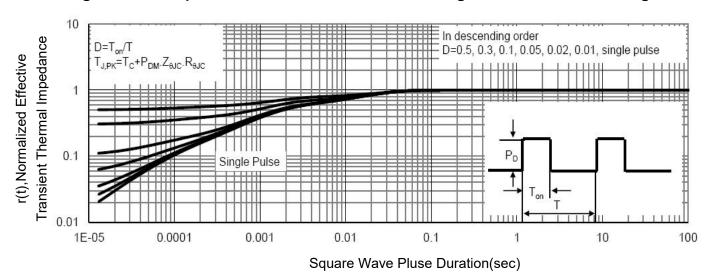
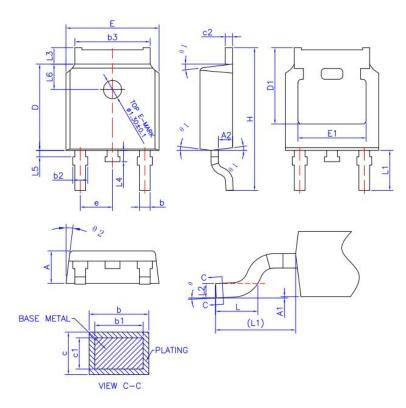


Figure 11 Normalized Maximum Transient Thermal Impedance



# **TO-252-2L Package Information**



# COMMON DIMENSIONS (UNITS OF MEASURE =MILLIMETER)

SYMBOL	MIN	MAX			
Α	2.20	2.30	2.38		
A1	0		0.10		
A2	0.90	1.01	1.10		
b	0.72		0.85		
b1	0.71	0.76	0.81		
b2	0.72		0.90		
b3	5.13	5.33	5.46		
C	0.47		0.60		
c1	0.46	0.51	0.56		
c2	0.47		0.60		
D	6.00	6.10	6.20		
D1	5.25				
E	6.50	6.60	6.70		
E1	4.70		4/15/2007		
е	2.186	2.286	2.386		
H	9.80	10.10	10.40		
L	1.40	1.50	1.70		
L1	2	2.90 REF			
L2	0.508 BSC				
L3	0.90		1.25		
L4	0.60	0.80	1.00		
L5	0.15		0.75		
L6	1.80 REF				
θ	0°		8°		
θ1	5°	7°	9°		
θ2	5°	7°	9°		



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